# **TOSHIBA**

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

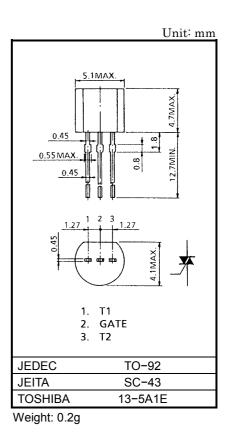
# SM1L43

### AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V<sub>DRM</sub> = 800V
- R.M.S. On–State Current : I<sub>T</sub> (RMS) = 1A

#### MAXIMUM RATINGS

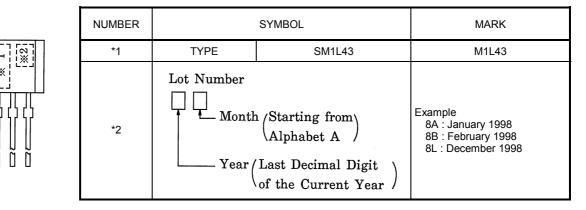
CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage	V <sub>DRM</sub>	800	V	
R.M.S. On-State Current (Full Sine Waveform Tc = 74°C)	IT (RMS)	1.0	А	
Peak One Cycle Surge On-State Current (Non-Repetitive)	l=a	8 (50Hz)	Α	
	ITSM	8.8 (60Hz)	A	
I <sup>2</sup> t Limit Value (t = 1~10ms)	l <sup>2</sup> t	0.32	A <sup>2</sup> s	
Peak Gate Power Dissipation	P <sub>GM</sub>	1	W	
Average Gate Power Dissipation	P <sub>G (AV)</sub>	0.1	W	
Peak Gate Voltage	V <sub>GM</sub>	6	V	
Peak Gate Current	I <sub>GM</sub>	0.5	А	
Junction Temperature	Тj	-40~125	°C	
Storage Temperature Range	T <sub>stg</sub>	-40~125	°C	



## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	CHARACTERISTIC SYMBOL TEST CONDITION		MIN	TYP.	MAX	UNIT		
Repetitive Peak Off-State Current		I <sub>DRM</sub>	V <sub>DRM</sub> = 800V		—	_	10	μA
Gate Trigger Voltage	I	V <sub>GT</sub>	V <sub>D</sub> =12V, R <sub>L</sub> = 20Ω	T2 (+) , Gate (+)	_	_	1.5	V
	Ш			T2 (+) , Gate (−)	_	_	1.5	
	Ш			T2 (-) , Gate (-)	_	_	1.5	
Gate Trigger Current	I	I <sub>GT</sub>	V <sub>D</sub> = 12V, R <sub>L</sub> = 20Ω	T2 (+) , Gate (+)	_	_	10	mA
	Ш			T2 (+) , Gate (−)	_	_	10	
	Ш			T2 (-) , Gate (-)	_	_	10	
Peak On-State Voltage		V <sub>TM</sub>	I <sub>TM</sub> = 1.5A		_	_	1.5	V
Gate Non-Trigger Voltage		V <sub>GD</sub>	V <sub>D</sub> = Rated, Tc = 125°C		0.2	_	_	V
Holding Current		Ι <sub>Η</sub>	V <sub>D</sub> = 12V, I <sub>TM</sub> = 1A		_	_	10	mA
Thermal Resistance Rth (ji		R <sub>th (j−c)</sub>	Junction to Case, AC		_	_	40	°C/W
Thermal Resistance		R <sub>th (j−a)</sub>	Junction to Ambient, AC		_	—	180	°C/W

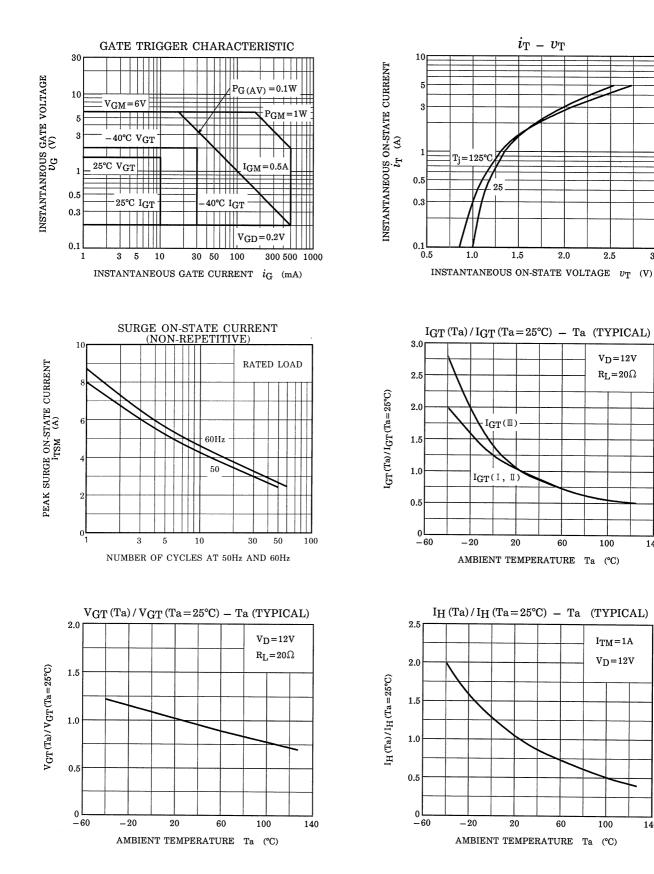
#### MARKING



## TOSHIBA

3.0

140



140

## **TOSHIBA**

0.5 0.5

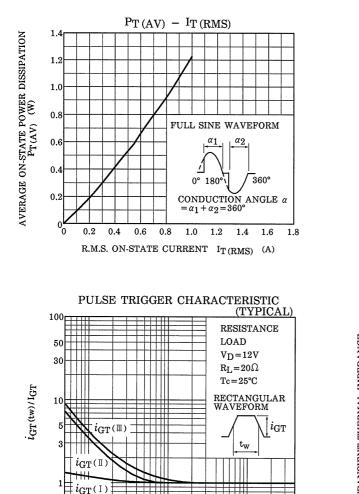
1

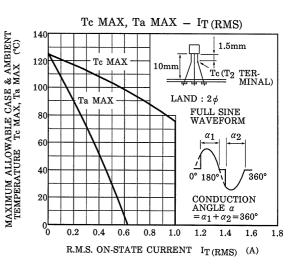
3

5 10

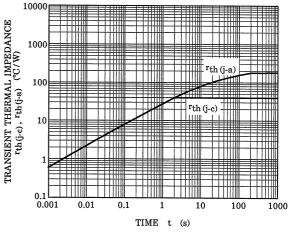
30 50 100

GATE TRIGGER PULSE WIDTH  $t_w$  ( $\mu s$ )





TRANSIENT THERMAL IMPEDANCE



300

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